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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/658,215	09/09/2003	Francois Roy	S1022.81038US00	2710
23628	7590 02/03/2005		EXAMINER	
WOLF GREENFIELD & SACKS, PC			VU, QUANG D	
FEDERAL RI 600 ATLANT	ESERVE PLAZA		ART UNIT	PAPER NUMBER
••••	A 02210-2211		2811	

DATE MAILED: 02/03/2005

Please find below and/or attached an Office communication concerning this application or proceeding.

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		Application No.	Applicant(s)	$\overline{\bigcirc}$		
Office Action Summary		10/658,215	ROY, FRANCOIS			
		Examin r	Art Unit			
		Quang D. Vu	2811			
The MAILING DATE of this concerns of the Period for Reply	ommunication ap	pears n the cover sheet with	h the c rrespondenc address			
A SHORTENED STATUTORY PER THE MAILING DATE OF THIS COI - Extensions of time may be available under the after SIX (6) MONTHS from the mailing date of - If the period for reply specified above is less tha If NO period for reply is specified above, the ma - Failure to reply within the set or extended perio Any reply received by the Office later than three earned patent term adjustment. See 37 CFR 1	MMUNICATION. provisions of 37 CFR 1. this communication. an thirty (30) days, a repaximum statutory period d for reply will, by statut e months after the mailir	136(a). In no event, however, may a reply within the statutory minimum of thirty will apply and will expire SIX (6) MONT e, cause the application to become ABA	oly be timely filed (30) days will be considered timely. HS from the mailing date of this communications. NDONED (35 U.S.C. § 133).	ation.		
Status						
1) Responsive to communicatio	n(s) filed on <u>27 S</u>	September 2004.				
2a) This action is FINAL .		s action is non-final.				
3) Since this application is in co	ince this application is in condition for allowance except for formal matters, prosecution as to the merits is					
closed in accordance with the	e practice under	Ex parte Quayle, 1935 C.D.	11, 453 O.G. 213.			
Disposition of Claims						
4) ⊠ Claim(s) <u>1-16</u> is/are pending 4a) Of the above claim(s) 5) □ Claim(s) is/are allowed 6) ⊠ Claim(s) <u>1-4,8-12 and 16</u> is/are 7) ⊠ Claim(s) <u>5-7 and 13-15</u> is/are 8) □ Claim(s) are subject to	is/are withdra d. are rejected. e objected to.	wn from consideration.				
Application Papers						
9)☐ The specification is objected t	to by the Examin	er.				
10)☐ The drawing(s) filed on			y the Examiner.			
Applicant may not request that a	any objection to the	drawing(s) be held in abeyand	e. See 37 CFR 1.85(a).			
Replacement drawing sheet(s) in	ncluding the correc	ction is required if the drawing(s) is objected to. See 37 CFR 1.12	21(d).		
11)☐ The oath or declaration is obj	ected to by the E	xaminer. Note the attached	Office Action or form PTO-152	2.		
Priority under 35 U.S.C. § 119						
a) Acknowledgment is made of a a) All b) Some * c) Nor 1. Certified copies of the 2. Certified copies of the 3. Copies of the certified application from the Int * See the attached detailed Office	ne of: priority documen priority documen copies of the pric ternational Burea	ts have been received. ts have been received in Ap prity documents have been r tu (PCT Rule 17.2(a)).	plication No eceived in this National Stage			
Attachment(s)						
 Notice of References Cited (PTO-892) D Notice of Draftsperson's Patent Drawing R 	Review (PTO-948)	4) Interview Su Paper No(s)	mmary (PTO-413) /Mail Date			
3) Information Disclosure Statement(s) (PTO Paper No(s)/Mail Date			ormal Patent Application (PTO-152)			

DETAILED ACTION

Claim Objections

Claim 14 is objected to because of the following informalities: The second claim 14 must be changed to claim 16. Appropriate correction is required.

Claim Rejections - 35 USC § 103

- 1. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
 - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 2. Claims 1-3, 8-11 and 16 are rejected under 35 U.S.C. 103(a) as being unpatentable over Applicant Admitted Prior Art (AAPA) in view of US Patent No. 5,163,179 to Pellegrini and US Patent No. 6,563,101 to Tullis.

Regarding claim 1, AAPA (figures 1-4) teaches a monolithic photodetector comprising: a first active area (10) of doped single-crystal silicon corresponding to first (D2) and second (D3) photodiodes having a same surface area as two charge transfer MOS transistors (M4, M5), and as one storage diode (D1), a cathode of each photodiode being connected to a cathode of the storage diode via one of the charge transfer MOS transistors;

a second active area (18) of doped single-crystal silicon arranged next to a portion of the first active area (10) associated with the second photodiode (D3) and corresponding to a

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precharge switch having a first terminal connected to the cathode of the storage diode (D1) and a second terminal connected to a reference voltage (33); and

a third active (20) doped single-crystal silicon area arranged next to the portion of the first active area (10) associated with the first photodiode (D2) and corresponding to two read MOS transistors (M2, M3) in series, the gate (GM2, GM3) of one of the read transistors being connected to the cathode of the storage diode (D1) and the drain (DM2, DM3) or the source (SM2, SM3) of one of the read transistors (M2, M3) being connected to a processing system.

AAPA differs from the claimed invention by not showing the surfaces of the second and third active areas exposed. However, Pellegrini teaches the active area of the photodecting is opened (exposed) (column 4, lines 52-55). Therefore, it would have been obvious to one having ordinary skill in the art at the time the invention was made to incorporate the teaching of Pellegrini into the device taught by AAPA in order to release the electrons from the photodiodes.

The combined device differs from the claimed invention by not showing the second and the third active areas are identical. However, Tullis teaches the areas of active areas are identical (column 8, lines 12-53). Therefore, it would have been obvious to one having ordinary skill in the art at the time the invention was made to incorporate the teaching of Tullis into the device taught by AAPA and Pellegrini in order to get the same gain of electrons in the active areas.

Regarding claim 2, the combined device shows the second (AAPA; 18) and third (AAPA; 20) active areas have substantially identical surface areas.

Regarding claim 3, the combined device shows the first, second, and third active areas (AAPA; 10, 18, 20) are rectangular, the second and third active areas (AAPA; 18, 20) being of

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same dimensions and substantially aligned at a same distance from a side of the first active area (AAPA; 10).

Regarding claim 8, the combined device shows the gates (AAPA; GM4, GM5) of the charge transfer MOS transistors (AAPA; M4, M5) correspond to portions of polysilicon strips (AAPA; 14, 16), which extend between the second and third active areas (AAPA; 18, 20).

Regarding claim 9, AAPA (figures 1-4) teaches a monolithic photodetector comprising:
a first active area (10) of doped single-crystal silicon including first (D2) and second (D3)
photodiodes having a same surface area as two charge transfer MOS transistors (M4, M5), and as
one storage diode (D1);

a second active area (18) of doped single-crystal silicon arranged next to a portion of the first active area (10) associated with the second photodiode (D3) and including a precharge switch; and

a third active doped (20) single-crystal silicon area arranged next to the portion of the first active area (10) associated with the first photodiode (D2) and including two read MOS transistors (M2, M3) in series.

AAPA differs from the claimed invention by not showing the surfaces of the second and third active areas exposed. However, Pellegrini teaches the active area of the photodecting is opened (exposed) (column 4, lines 52-55). Therefore, it would have been obvious to one having ordinary skill in the art at the time the invention was made to incorporate the teaching of Pellegrini into the device taught by AAPA in order to release the electrons from the photodiodes.

The combined device differs from the claimed invention by not showing the second and the third active areas are identical. However, Tullis teaches the areas of active areas are identical

(column 8, lines 12-53). Therefore, it would have been obvious to one having ordinary skill in the art at the time the invention was made to incorporate the teaching of Tullis into the device taught by AAPA and Pellegrini in order to get the same gain of electrons in the active areas.

Regarding claim 10, the combined device shows the second (AAPA; 18) and third (AAPA; 20) active areas have substantially identical surface areas.

Regarding claim 11, the combined device shows the first, second, and third active areas (AAPA; 10, 18, 20) are rectangular, the second and third active areas (AAPA; 18, 20) being of same dimensions and substantially aligned at a same distance from a side of the first active area (AAPA; 10).

Regarding claim 16, the combined device shows the gates (AAPA; GM4, GM5) of the charge transfer MOS transistors (AAPA; M4, M5) correspond to portions of polysilicon strips (AAPA; 14, 16), which extend between the second and third active areas (AAPA; 18, 20).

3. Claims 4 and 12 are rejected under 35 U.S.C. 103(a) as being unpatentable over Applicant Admitted Prior Art (AAPA) and Pellegrini in view of Tullis, and further in view of US Patent No. 6,392,279 to Toyofuku.

Regarding claim 4, the disclosures of AAPA, Pellegrini and Tullis are discussed as applied to claims 1-3 and 8 above.

The combined device differs from the claimed invention by not showing a MOS transistor with two parallel gates. However, Toyofuku (figures 1A-2C) teaches MOS transistor with dual gates (7g). Therefore, it would have been obvious to one having ordinary skill in the art at the time the invention was made to incorporate the teaching of Toyofuku into the device taught by

AAPA, Pellegrini and Tullis in order to improve the short-channel effects and provide high current drive between two gates.

Regarding claim 12, the disclosures of AAPA, Pellegrini and Tullis are discussed as applied to claims 9-11 and 16 above.

The combined device differs from the claimed invention by not showing a MOS transistor with two parallel gates. However, Toyofuku (figures 1A-2C) teaches MOS transistor with dual gates (7g). Therefore, it would have been obvious to one having ordinary skill in the art at the time the invention was made to incorporate the teaching of Toyofuku into the device taught by AAPA, Pellegrini and Tullis in order to improve the short-channel effects and provide high current drive between two gates.

Allowable Subject Matter

Claims 5-7 and 13-15 are objected to as being dependent upon a rejected base claim, but would be allowable if rewritten in independent form including all of the limitations of the base claim and any intervening claims.

Response to Arguments

Applicant's arguments with respect to claims 1-8 have been considered but are moot in view of the new ground(s) of rejection.

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Conclusion

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Quang D. Vu whose telephone number is 571-272-1667. The examiner can normally be reached on Monday-Friday.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Eddie Lee can be reached on 571-272-1732. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

qv January 26, 2005

> EDDIE LEE SUPERVISORY PATENT EXAMINER TECHNOLOGY CENTER 2800